NSN 5961-01-043-4776

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Inclosure Material:

Metal

Overall Length:

Between 0.460 inches and 0.505 inches

Overall Height:

Between 0.140 inches and 0.190 inches

Overall Width:

Between 0.340 inches and 0.420 inches

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

110.0 breakdown voltage, collector-to-base, emitter open and 110.0 breakdown voltage, collector-to-emitter, base open and 5.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current

Power Rating Per Characteristic:

16.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

80131-release6485 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0